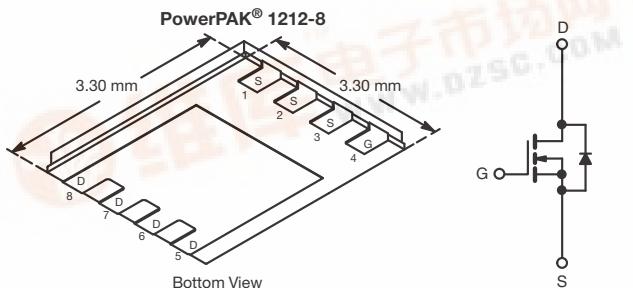


Automotive N-Channel 30 V (D-S) 175 °C MOSFET

PRODUCT SUMMARY	
V_{DS} (V)	30
$R_{DS(on)}$ (Ω) at $V_{GS} = 10$ V	0.013
$R_{DS(on)}$ (Ω) at $V_{GS} = 4.5$ V	0.015
I_D (A)	16
Configuration	Single



Part Marking Code: Q003

N-Channel MOSFET

FEATURES

- Halogen-free According to IEC 61249-2-21 Definition
- TrenchFET® Power MOSFET
- Compliant to RoHS Directive 2002/95/EC
- AEC-Q101 Qualified^d
- Find out more about Vishay's Automotive Grade Product Requirements at: www.vishay.com/applications



RoHS
COMPLIANT
HALOGEN
FREE

ORDERING INFORMATION

Package	PowerPAK 1212-8
Lead (Pb)-free and Halogen-free	SQS404EN-T1-GE3

ABSOLUTE MAXIMUM RATINGS ($T_C = 25$ °C, unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNIT
Drain-Source Voltage		V_{DS}	30	V
Gate-Source Voltage		V_{GS}	± 12	
Continuous Drain Current ^a	$T_C = 25$ °C	I_D	16	A
	$T_C = 125$ °C		16	
Continuous Source Current (Diode Conduction) ^a		I_S	16	A
Pulsed Drain Current ^b		I_{DM}	64	
Single Pulse Avalanche Current	$L = 0.1$ mH	I_{AS}	29	mJ
Single Pulse Avalanche Energy		E_{AS}	42	
Maximum Power Dissipation ^b	$T_C = 25$ °C	P_D	62.5	W
	$T_C = 125$ °C		20	
Operating Junction and Storage Temperature Range		T_J, T_{stg}	- 55 to + 175	°C
Soldering Recommendations (Peak Temperature) ^{e, f}			260	

THERMAL RESISTANCE RATINGS

PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-Ambient	PCB Mount ^c	R_{thJA}	81	°C/W
Junction-to-Case (Drain)		R_{thJC}	2.4	

Notes

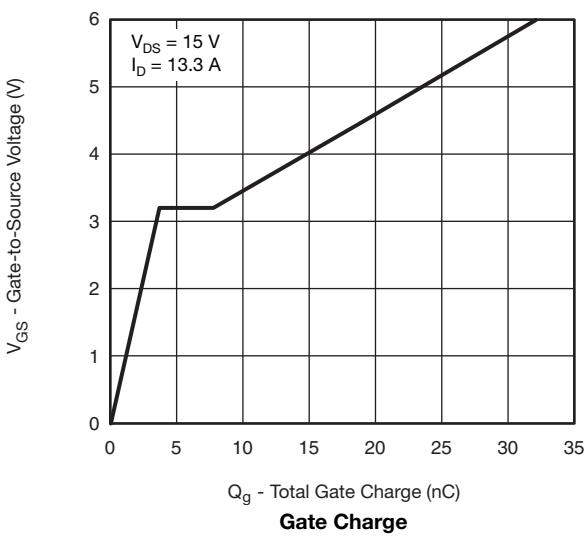
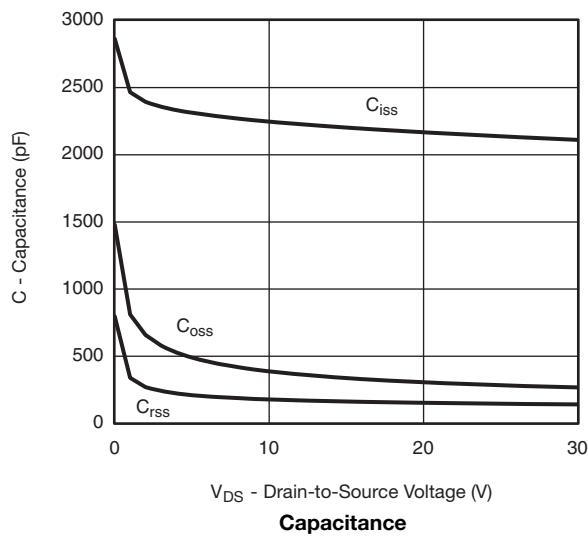
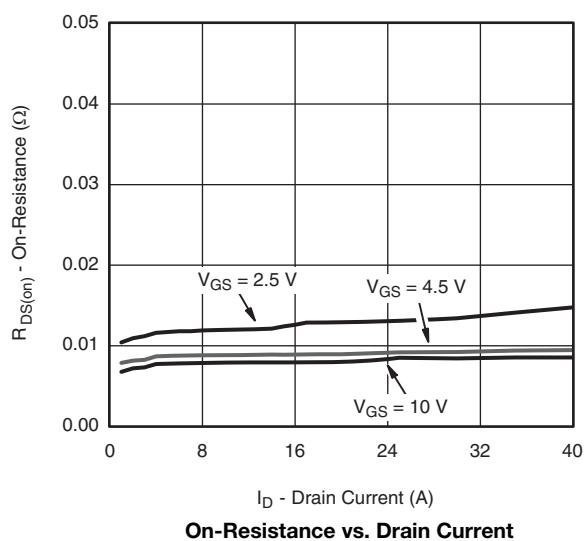
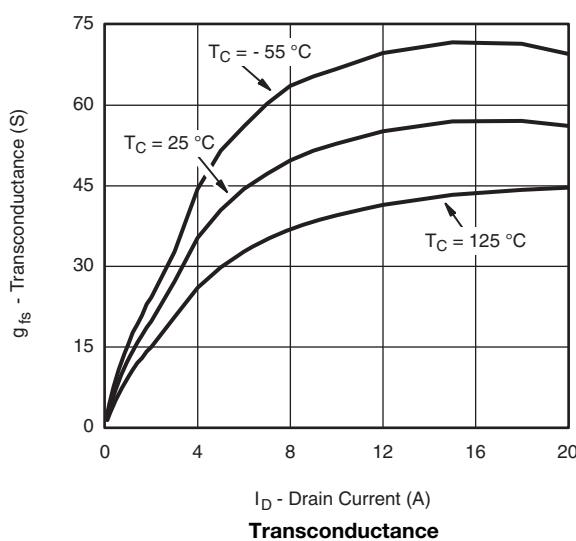
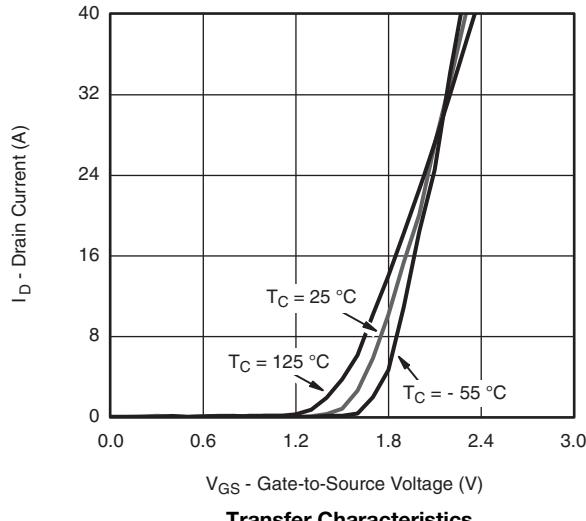
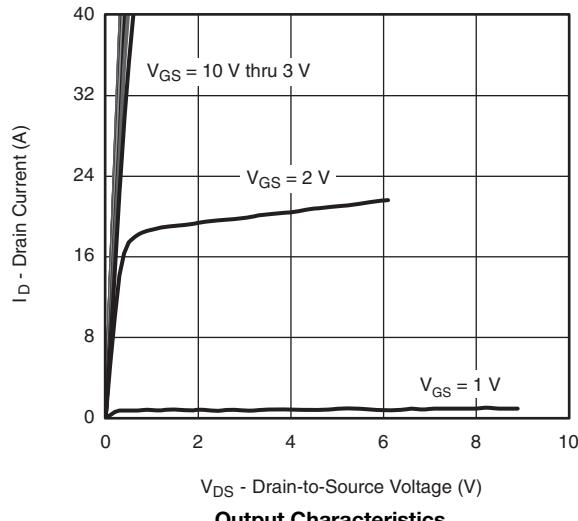
- Package limited.
- Pulse test; pulse width ≤ 300 μ s, duty cycle ≤ 2 %.
- When mounted on 1" square PCB (FR-4 material).
- Parametric verification ongoing.
- See solder profile (www.vishay.com/ppg?73257). The PowerPAK 1212-8 is a leadless package. The end of the lead terminal is exposed copper (not plated) as a result of the singulation process in manufacturing. A solder fillet at the exposed copper tip cannot be guaranteed and is not required to ensure adequate bottom side solder interconnection.
- Rework conditions: manual soldering with a soldering iron is not recommended for leadless components.

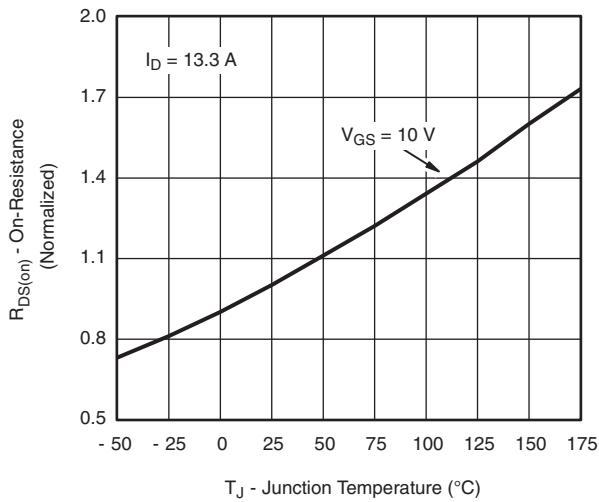
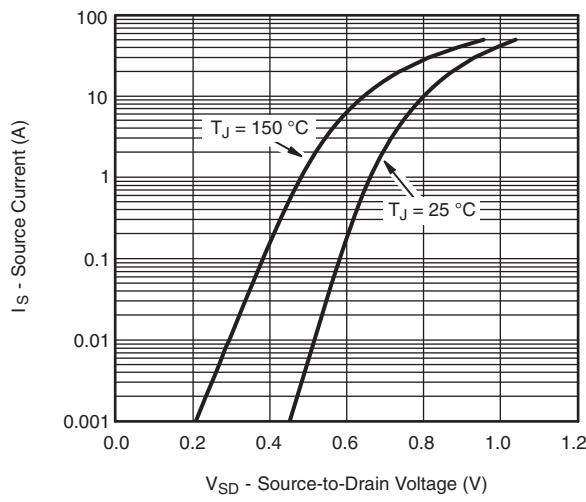
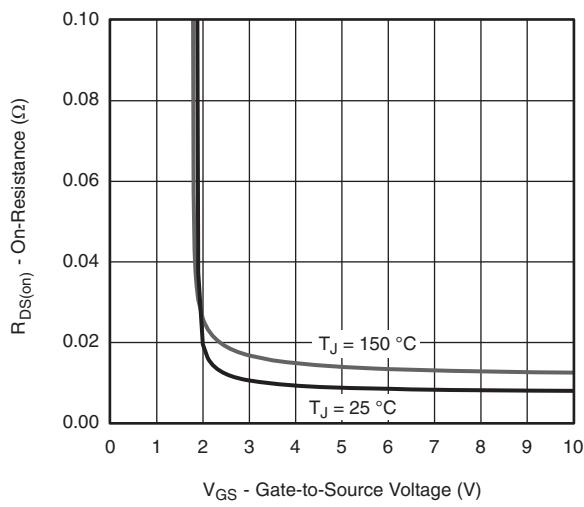
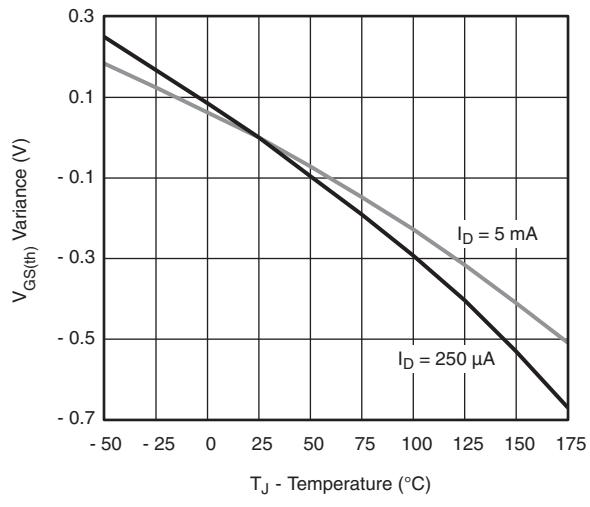
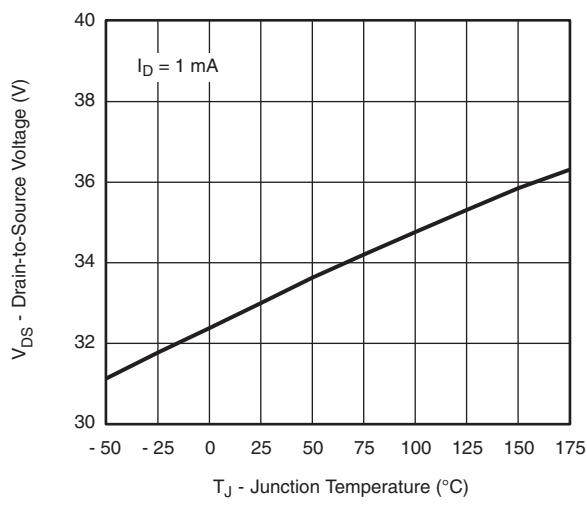
SPECIFICATIONS ($T_C = 25^\circ\text{C}$, unless otherwise noted)								
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT	
Static								
Drain-Source Breakdown Voltage	V_{DS}	$V_{GS} = 0 \text{ V}, I_D = 250 \mu\text{A}$		30	-	-	V	
Gate-Source Threshold Voltage	$V_{GS(\text{th})}$	$V_{DS} = V_{GS}, I_D = 250 \mu\text{A}$		1.5	2.0	2.5		
Gate-Source Leakage	I_{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 12 \text{ V}$		-	-	± 100	nA	
Zero Gate Voltage Drain Current	I_{DSS}	$V_{GS} = 0 \text{ V}$	$V_{DS} = 30 \text{ V}$	-	-	1	μA	
		$V_{GS} = 0 \text{ V}$	$V_{DS} = 30 \text{ V}, T_J = 125^\circ\text{C}$	-	-	50		
		$V_{GS} = 0 \text{ V}$	$V_{DS} = 30 \text{ V}, T_J = 175^\circ\text{C}$	-	-	150		
On-State Drain Current ^a	$I_{D(\text{on})}$	$V_{GS} = 10 \text{ V}$	$V_{DS} \geq 5 \text{ V}$	20	-	-	A	
Drain-Source On-State Resistance ^a	$R_{DS(\text{on})}$	$V_{GS} = 10 \text{ V}$	$I_D = 10 \text{ A}$	-	0.008	0.013	Ω	
		$V_{GS} = 4.5 \text{ V}$	$I_D = 7 \text{ A}$	-	0.009	0.015		
		$V_{GS} = 10 \text{ V}$	$I_D = 10 \text{ A}, T_J = 125^\circ\text{C}$	-	0.013	0.019		
		$V_{GS} = 10 \text{ V}$	$I_D = 10 \text{ A}, T_J = 175^\circ\text{C}$	-	0.015	0.023		
Forward Transconductance ^b	g_{fs}	$V_{DS} = -15 \text{ V}, I_D = 10 \text{ A}$		-	50	-	S	
Dynamic^b								
Input Capacitance	C_{iss}	$V_{GS} = 0 \text{ V}$	$V_{DS} = 15 \text{ V}, f = 1 \text{ MHz}$	-	2200	2650	pF	
Output Capacitance	C_{oss}			-	335	405		
Reverse Transfer Capacitance	C_{rss}			-	160	200		
Total Gate Charge ^c	Q_g	$V_{GS} = 4.5 \text{ V}$	$V_{DS} = 15 \text{ V}, I_D = 13.3 \text{ A}$	-	19.2	28	nC	
Gate-Source Charge ^c	Q_{gs}			-	3.7	5.5		
Gate-Drain Charge ^c	Q_{gd}			-	4.1	6.2		
Turn-On Delay Time ^c	$t_{d(on)}$			-	9	11		
Rise Time ^c	t_r	$V_{DD} = 15 \text{ V}, R_L = 15 \Omega$ $I_D \equiv 1 \text{ A}, V_{GEN} = 10 \text{ V}, R_g = 6 \Omega$				-	ns	
Turn-Off Delay Time ^c	$t_{d(off)}$					-		
Fall Time ^c	t_f					-		
Source-Drain Diode Ratings and Characteristics^b								
Pulsed Current ^a	I_{SM}			-	-	64	A	
Forward Voltage	V_{SD}	$I_F = 8.8 \text{ A}, V_{GS} = 0 \text{ V}$		-	0.8	1.2	V	

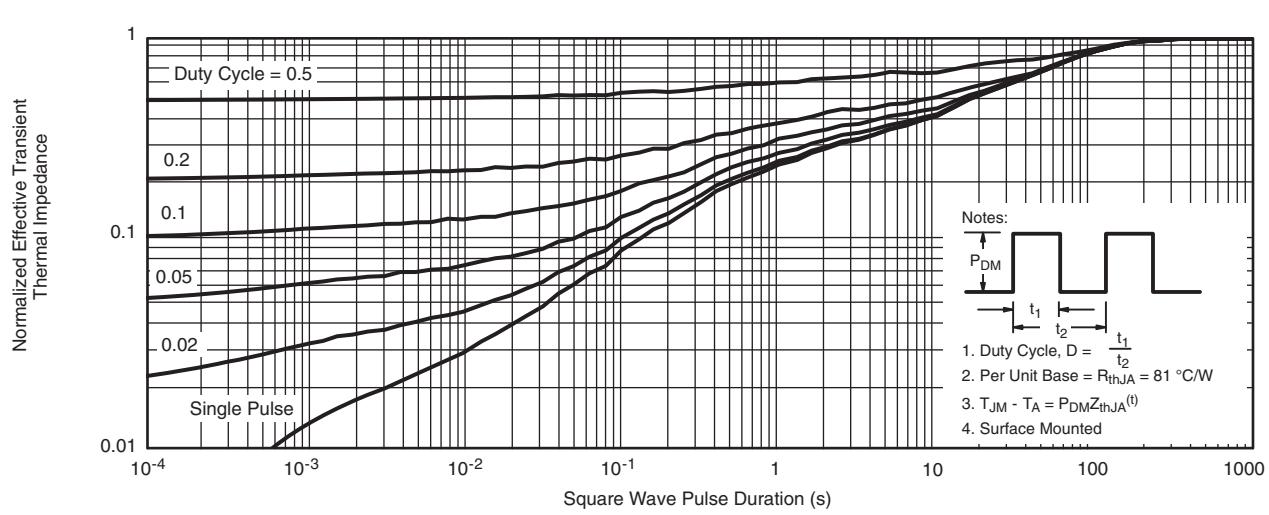
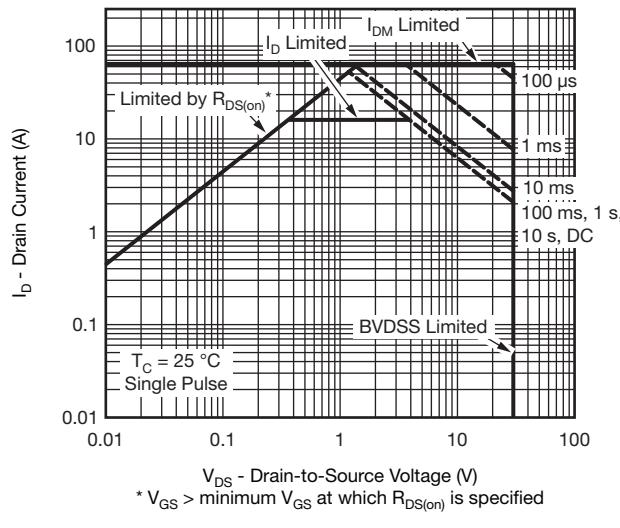
Notes

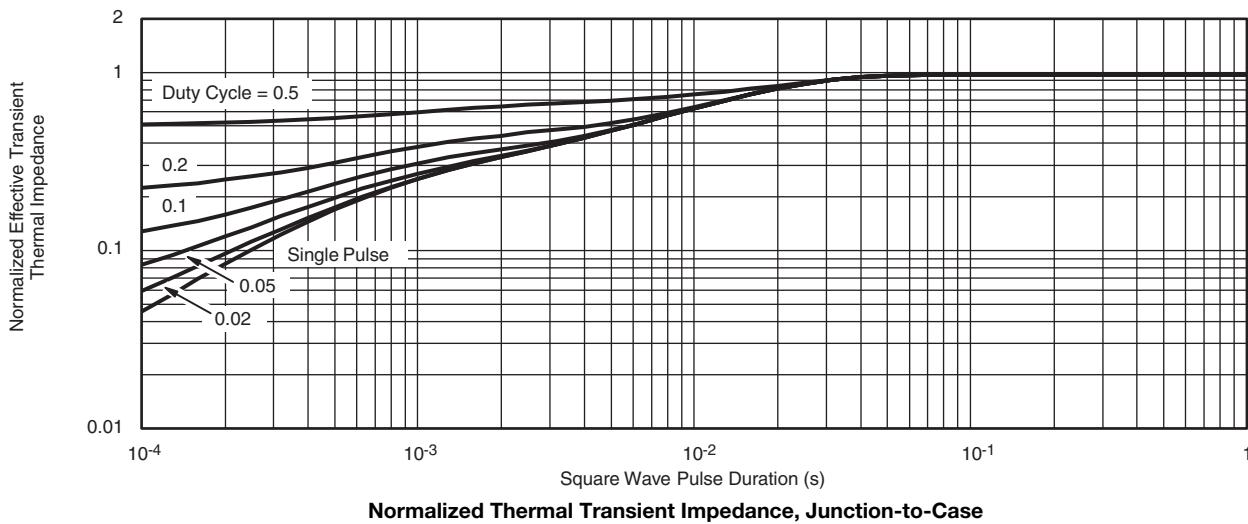
- a. Pulse test; pulse width $\leq 300 \mu\text{s}$, duty cycle $\leq 2 \%$.
- b. Guaranteed by design, not subject to production testing.
- c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$, unless otherwise noted)

TYPICAL CHARACTERISTICS ($T_A = 25^\circ\text{C}$, unless otherwise noted)**On-Resistance vs. Junction Temperature****Source Drain Diode Forward Voltage****On-Resistance vs. Gate-to-Source Voltage****Threshold Voltage****Drain Source Breakdown vs. Junction Temperature**

THERMAL RATINGS ($T_A = 25^\circ\text{C}$, unless otherwise noted)


THERMAL RATINGS ($T_A = 25^\circ\text{C}$, unless otherwise noted)**Note**

- The characteristics shown in the two graphs
 - Normalized Transient Thermal Impedance Junction-to-Ambient (25°C)
 - Normalized Transient Thermal Impedance Junction-to-Case (25°C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions.

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